MP2153D



2.5V to 5.5V, 3A, Synchronous, Step-Down **Converter with Fast Output Discharge**

DESCRIPTION

The MP2153D is a monolithic, step-down switch-mode converter with integrated internal power MOSFETs. It can achieve up to 3A of continuous output current (I_{OUT}) across a wide 2.5V to 5.5V input voltage (VIN) range, with excellent load and line regulation. The output voltage (V_{OUT}) can be regulated to as low as 0.6V.

The device is ideal for a wide range of applications. including solid-state drives (SSDs), portable devices, as well as other lowpower and low-voltage systems.

Constant-on-time (COT) control provides fast transient response and eases loop stabilization.

Full protection features include cycle-by-cycle over-current protection (OCP), over-voltage protection (OVP), short-circuit protection (SCP) with hiccup mode, and thermal shutdown.

The MP2153D requires a minimal number of available. standard readily external components, and is available in an ultra-small SOT563 package and UTQFN-6 а (1.2mmx1.6mm) package.

FEATURES

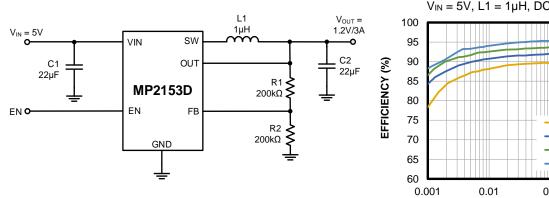
- Wide 2.5V to 5.5V Operating Input Voltage (VIN) Range
- Up to 3A Output Current (I_{OUT})
- Adjustable Output Voltage (VOUT) from 0.6V
- 25µA Low Quiescent Current (I_o)
- 1.1MHz Switching Frequency (f_{SW})
- Enable (EN) for Power Sequencing
- 1% Feedback (FB) Accuracy
- $65m\Omega$ and $35m\Omega$ Internal Power MOSFETs •
- 100% Duty Cycle •
- Fast Output Discharge •
- Output Over-Voltage Protection (OVP) •
- Short-Circuit Protection (SCP) with Hiccup • Mode
- Thermal Shutdown
- Available in an SOT563 Package and UTQFN-6 (1.2mmx1.6mm) Package
 - **Optimized Performance with MPS** - MPL Inductor MPL-AL4020 Series

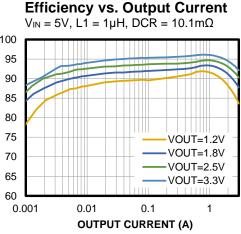
APPLICATIONS

- Solid-State Drives (SSDs)
- Portable Instruments
- **Battery-Powered Devices**
- Multi-Functional Printers

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TYPICAL APPLICATION







ORDERING INFORMATION

Part Number*	Package	Top Marking	Vout Range	MSL Rating
MP2153DGQFU	UTQFN-6 (1.2mmx1.6mm)	See Below	Adjustable	1
MP2153DGTF	SOT563	See Below	Adjustable	1

* For Tape & Reel, add suffix -Z (e.g. MP2153DGTF-Z).

TOP MARKING (MP2153DGQFU)

KT LL

KT: Product code of MP2153DGQFU LL: Lot number

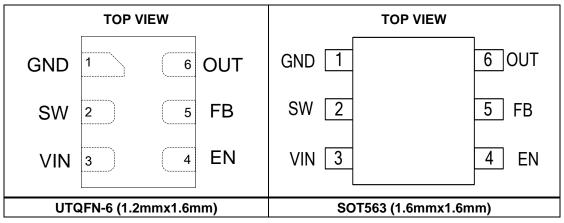
TOP MARKING (MP2153DGTF)

BNZY

LLL

BNZ: Product code of MP2153DGTF Y: Year code LLL: Lot number

PACKAGE REFERENCE





PIN FUNCTIONS

Pin #	SOT563 (Adjustable Version)	Description
1	GND	Power ground.
2	SW	Output switching node. The SW pin is the drain of the internal, P-Channel high-side MOSFET (HS-FET). Connect SW to the inductor to complete the converter.
3	VIN	Supply voltage. The MP2153D operates from a 2.5V to 5.5V unregulated input voltage (V_{IN}) . Use a decoupling capacitor to prevent large voltage spikes at the input.
4	EN	On/off control.
5	FB	Feedback. To set the output voltage (V _{OUT}), connect an external resistor divider tapped to the FB pin between the output and GND.
6	OUT	Output sense. The OUT pin is the voltage power rail and input sense for V _{OUT} . Use an output capacitor (C2) to reduce the output voltage ripple (Δ V _{OUT}).

ABSOLUTE MAXIMUM RATINGS (1)

Supply voltage (VIN)	6.5V
V _{SW}	-0.3V (-5V for <10ns) to
	+6.5V (10V for <10ns)
All other pins	0.3V to +6.5V
Junction temperature	150°C
Lead temperature	260°C
Continuous power dissip	Dation $(T_A = 25^{\circ}C)^{(2)(4)}$
SOT563	1.5 W
UTQFN (1.2mmx1.6mm) 2W ^{(2) (5)}
Storage temperature	65°C to +150°C

ESD Rating

SOT563

Human body model (HBM)	. 2000V
Charged device model (CDM)	.1500V
UTQFN-6 (1.2mmx1.6mm)	
Human body model (HBM)	. 2000V
Charged device model (CDM)	.1500V

Recommended Operating Conditions ⁽³⁾

Supply voltage (VIN)	2.5V to 5.5V
Operating junction temp ((T _J)40°C to +125°C

UTQFN-6 (1.2mmx1.6mm)		
EVL2153D-QFU-00A (5)	65	30
°C/W		
JESD51-7 ⁽⁶⁾⁽⁷⁾⁽⁸⁾	173	127 °C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-toambient thermal resistance θ_{JA} , and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = (T_J (MAX) - T_A) / θ_{JA} . Exceeding the maximum allowable power dissipation can produce an excessive die temperature, which may cause the device to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on EVL2193D-TF-00A, 2-layer PCB.
- 5) Measured on EVL2153D-QFU-00A, 2-layer PCB.
- 6) Measured on JESD51-7, 4-layer PCB.
- 7) The value of θ_{JA} given in this table is only valid for comparison with other packages and cannot be used for design purposes.
- These values are calculated in accordance with JESD51-7, and simulated on a specified JEDEC board. They do not represent the performance obtained in an actual application.



ELECTRICAL CHARACTERISTICS

 V_{IN} = 3.6V, T_J = -40°C to +125°C ⁽⁹⁾, typical value is tested at T_J = 25°C. The over-temperature (OT) limit is guaranteed by characterization, unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Max	Units
Input voltage	Vin		2.5		5.5	V
Under-voltage lockout (UVLO) rising threshold	VUVLO_RISING			2.3	2.45	V
UVLO threshold hysteresis	VUVLO_HYS			200		mV
Feedback (FB) voltage	V _{FB}	2.5V ≤ V _{IN} ≤ 5.5V T _J = -40°C to +125°C	594 591	600 600	606 609	mV
FB current	I _{FB}	$V_{FB} = 0.63V$		50	100	nA
P-channel high-side MOSFET (HS-FET) on resistance	R _{DS(ON)_} HS	V _{IN} = 5V		65		mΩ
N-channel low-side MOSFET (LS-FET) on resistance	Rds(on)_ls	$V_{IN} = 5V$		35		mΩ
Switch leakage		$\label{eq:VSW} \begin{array}{l} V_{SW} = 0V \text{ and } 6V, \ V_{EN} = 0V, \\ V_{IN} = 6V, \ T_J = 25^\circ C \end{array}$		0	1	μA
HS-FET peak current limit	I _{PEAK_HS}		4		6	А
LS-FET valley current limit	IPEAK_LS			3.5		A
Zero-current detection (ZCD)				50		mA
On time	t _{ON}	V _{IN} = 5V, V _{OUT} = 1.2V V _{IN} = 3.6V, V _{OUT} = 1.2V	180 240	220 300	260 360	ns
Switching frequency	fsw	$V_{OUT} = 1.2V$		1100		kHz
Minimum off time	t _{MIN_OFF}			100		ns
Minimum on time ⁽¹⁰⁾	t _{MIN_ON}			60		ns
Soft-start time	tss	10% to 90% Vоuт rise		0.5		ms
Enable (EN) start-up delay		EN on to SW active		150		μs
EN input logic low voltage					0.4	V
EN input logic high voltage			1.2			V
Output discharge resistor	Rdischarge	V _{EN} = 0V, V _{OUT} = 1.2V		13		Ω
		$V_{EN} = 2V$		1.2		μA
EN input current		$V_{EN} = 0V$		0		μA
Shutdown current	I _{SD}	$V_{EN} = 0V, T_J = 25^{\circ}C$		0	1	μA
Quiescent current	lQ	$V_{EN} = 2V, V_{FB} = 0.63V, V_{IN} = 5V, T_J = 25^{\circ}C$		25	30	μA
Output over-voltage protection (OVP) threshold	Vovp		110	115	120	% of V _{FB}
Output OVP hysteresis	V _{OVP_HYS}			10		% of V _{FB}
OVP delay	t _{DELAY_OVP}			12		μs
LS-FET current		Current flow from SW to GND		1.5		А
Absolute input voltage (V _{IN}) OVP threshold		After VOUT OVP is enabled		6.1		V
Absolute VIN OVP hysteresis				400		mV
Thermal shutdown (10)	T _{SD}			160		°C
Thermal hysteresis (10)				30		°C

Notes:

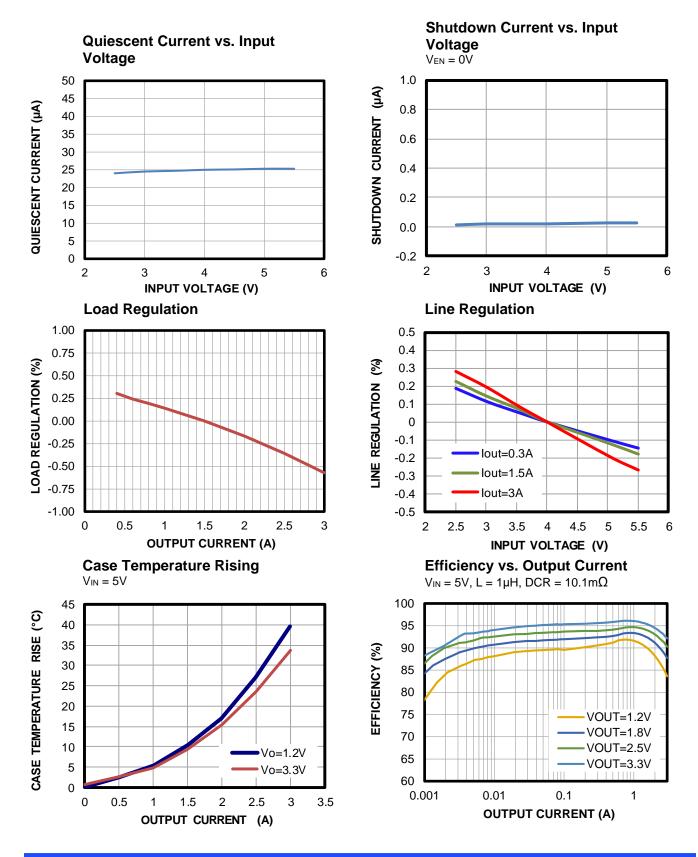
9) Guaranteed by over-temperature correlation. Not tested in production.

10) Guaranteed by engineering sample characterization.



TYPICAL CHARACTERISTICS

 V_{IN} = 3.6V, V_{OUT} = 1.2V, L = 1µH, C_{OUT} = 22µF, T_A = 25°C, unless otherwise noted.



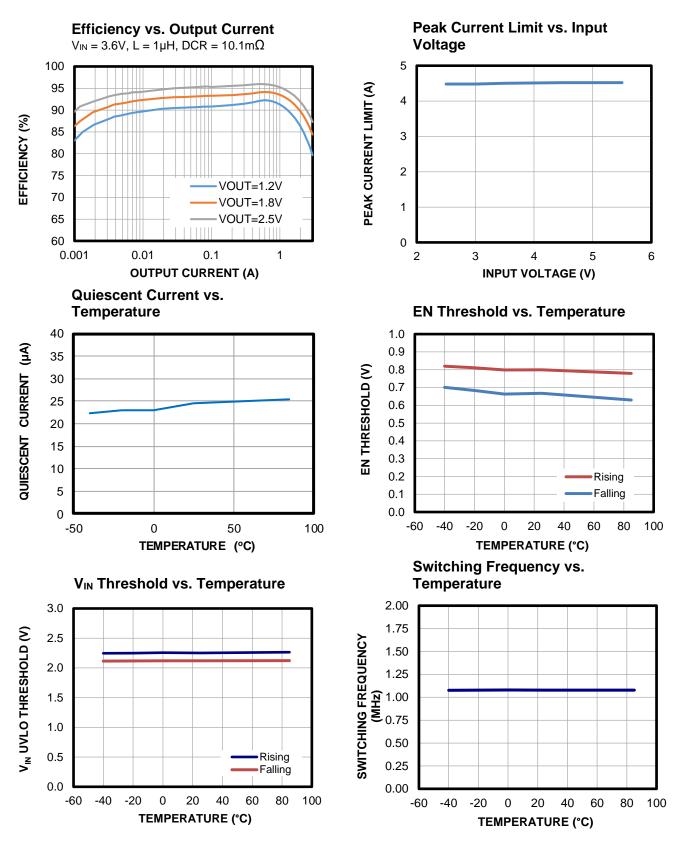
MP2153D Rev. 1.0 2/15/2022 N

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TYPICAL CHARACTERISTICS (continued)

 V_{IN} = 3.6V, V_{OUT} = 1.2V, L = 1µH, C_{OUT} = 22µF, T_A = 25°C, unless otherwise noted.



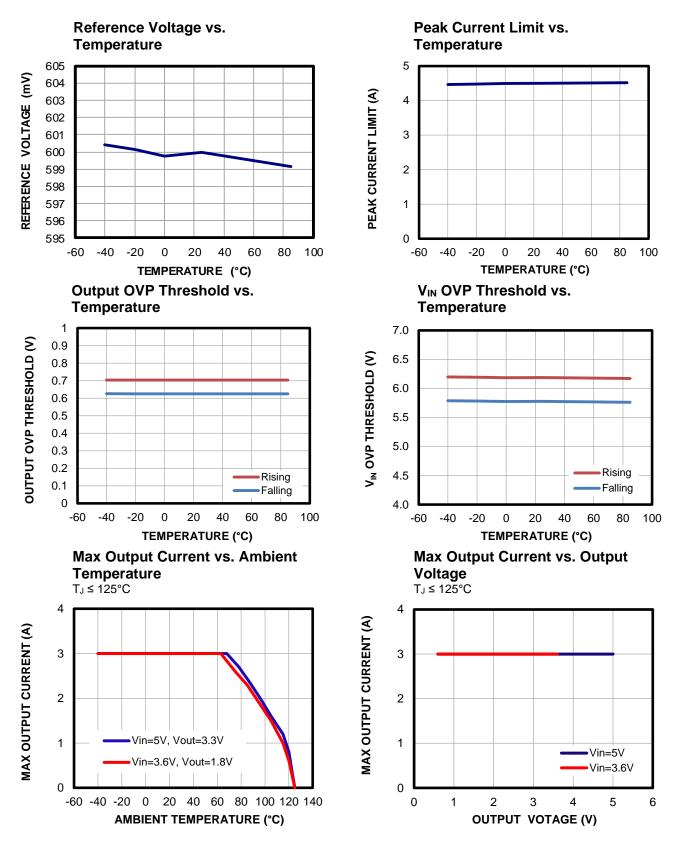
MP2153D Rev. 1.0 2/15/2022 M

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TYPICAL CHARACTERISTICS (continued)

 V_{IN} = 3.6V, V_{OUT} = 1.2V, L = 1µH, C_{OUT} = 22µF, T_A = 25°C, unless otherwise noted.



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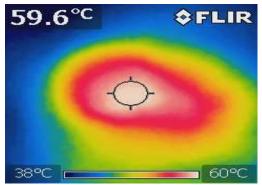


TYPICAL CHARACTERISTICS (continued)

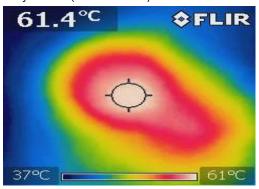
 V_{IN} = 3.6V, V_{OUT} = 1.2V, L = 1µH, C_{OUT} = 22µF, T_A = 25°C, unless otherwise noted.

Thermal Image

 $V_{IN} = 5V$, $V_{OUT} = 1.2V$, $I_{OUT} = 3A$, 2-layer PCB (64mmx64mm)

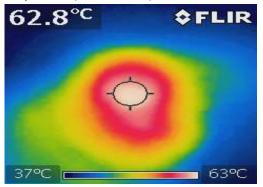


Thermal Image $V_{IN} = 5V$, $V_{OUT} = 1.8V$, $I_{OUT} = 3A$, 2-layer PCB (64mmx64mm)

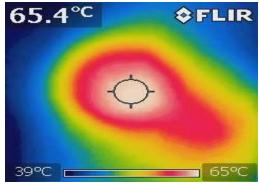


Thermal Image

V_{IN} = 5V, V_{OUT} = 2.5V, I_{OUT} = 3A, 2-layer PCB (64mmx64mm)



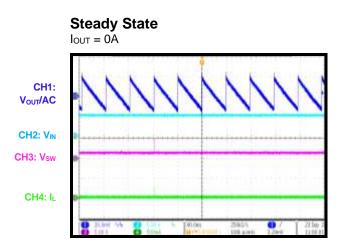
Thermal Image $V_{IN} = 5V$, $V_{OUT} = 3.3V$, $I_{OUT} = 3A$, 2-layer PCB (64mmx64mm)

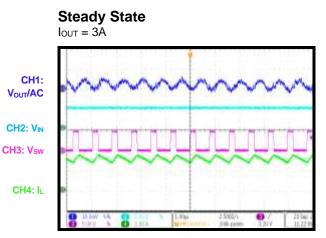




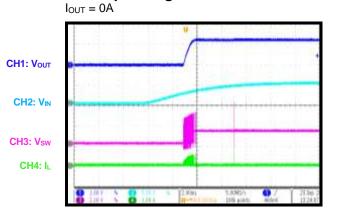
TYPICAL PERFORMANCE CHARACTERISTICS

 $V_{IN} = 5V$, $V_{OUT} = 1.2V$, $L = 1\mu$ H, $C_{OUT} = 22\mu$ F, $T_A = 25^{\circ}$ C, unless otherwise noted.

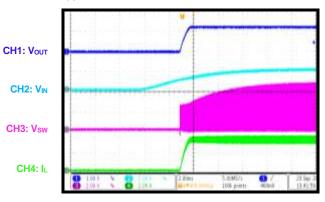


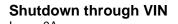


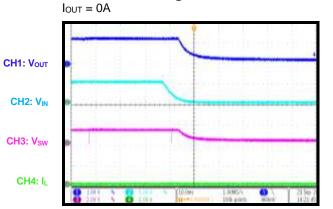
Start-Up through VIN

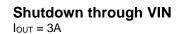


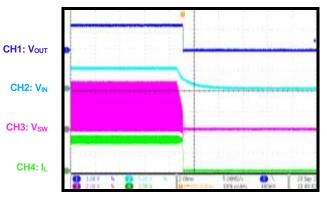
Start-Up through VIN $I_{OUT} = 3A$







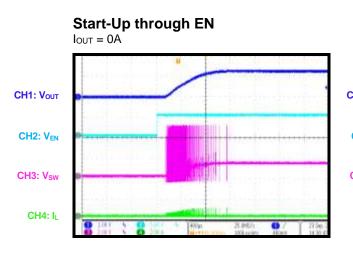


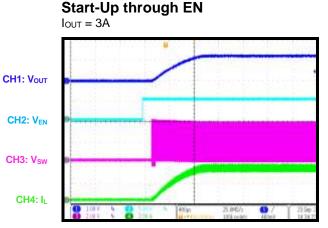




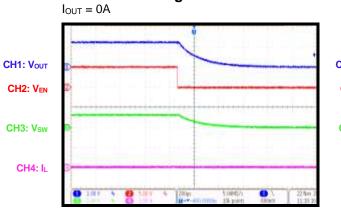
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 $V_{IN} = 5V$, $V_{OUT} = 1.2V$, $L = 1\mu H$, $C_{OUT} = 22\mu F$, $T_A = 25^{\circ}C$, unless otherwise noted.

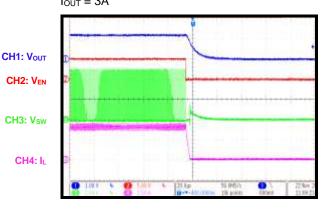




Shutdown through EN

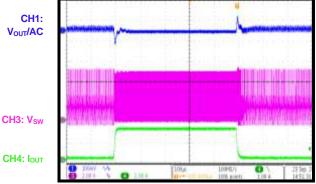


Shutdown through EN





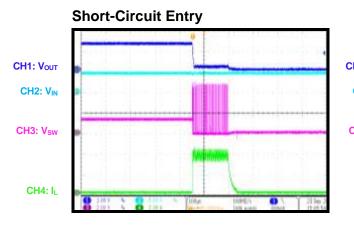


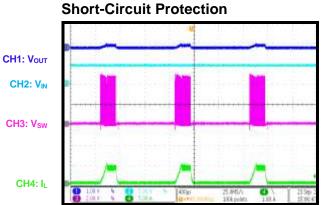




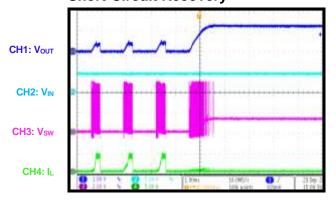
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 $V_{IN} = 5V$, $V_{OUT} = 1.2V$, $L = 1\mu$ H, $C_{OUT} = 22\mu$ F, $T_A = 25^{\circ}$ C, unless otherwise noted.





Short-Circuit Recovery





FUNCTIONAL BLOCK DIAGRAM

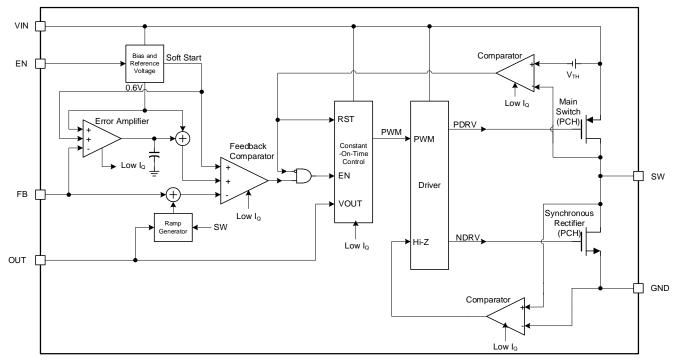


Figure 1: Functional Block Diagram



OPERATION

The MP2153D employs constant-on-time control (COT) and input voltage (V_{IN}) feed-forward to stabilize the switching frequency (f_{SW}) across the entire V_{IN} range. The device can achieve up to 3A of continuous output current (I_{OUT}) across a wide 2.5V to 5.5V V_{IN} range, with excellent load and line regulation. The output voltage (V_{OUT}) can be regulated to as low as 0.6V.

Constant-On-Time (COT) Control

Constant-on-time (COT) control offers a simpler control loop and fast transient response, compared to fixed-frequency pulse-width modulation (PWM) control. By using V_{IN} feed-forward, the MP2153D can maintain a fairly constant f_{SW} across the entire V_{IN} and V_{OUT} ranges. The switching pulse on time (t_{ON}) can be estimated with Equation (1):

$$t_{\rm ON} = \frac{V_{\rm OUT}}{V_{\rm IN}} \times 0.91 \mu s \tag{1}$$

The IC has a fixed minimum off time (t_{MIN_OFF}) (100ns) to prevent inductor current (I_L) runaway during load transient.

Sleep Mode

The MP2153D employs sleep mode for high efficiency at extremely light loads. In sleep mode, most of the circuit blocks are turned off to reduce the input current to a minimum value (see Figure 2). The error amplifier (EA) and the PWM comparator remain on during sleep mode.

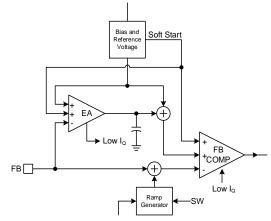


Figure 2: Operation Blocks in Sleep Mode

As the load decreases, the output voltage ripple (ΔV_{OUT}) increases and drives the EA output (EAO) low. If the EAO reaches its internal low threshold, then it clamps at this level and the device enters sleep mode. During sleep mode, the vallev of the feedback (FB) voltage (V_{FB}) is regulated to the internal reference voltage (V_{REF}) . This means that the average V_{OUT} is slightly exceeds the VOUT in discontinuous conduction mode (DCM) continuous or conduction mode (CCM). The on-time pulse in sleep mode is longer than that in DCM or CCM. Figure 3 shows the relationship between the average V_{FB} and V_{REF} in sleep mode.

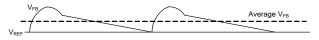


Figure 3: Average VFB in Sleep Mode

In sleep mode, the average V_{OUT} exceeds the internal V_{REF} . The EAO is clamped low. If the load increases, the PWM switching t_{ON} decreases to regulate V_{OUT} . ΔV_{OUT} decreases relatively. Once the EAO exceeds its internal low threshold, the IC exits sleep mode and enters either DCM or CCM, depending on the load. In DCM or CCM, the EA regulates the average V_{OUT} to the internal V_{REF} (see Figure 4).

VER + Ramp FAO

Figure 4: Discontinuous Conduction Mode

Due to the EA's clamping response time, there is a loading hysteresis while entering or exiting sleep mode.

Advanced Asynchronous Modulation (AAM) Mode under Light-Load Conditions

The MP2153D employs advanced asynchronous modulation (AAM) power-save mode and zero current detection (ZCD) for light-load operation (see Figure 5).

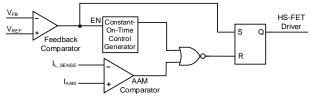


Figure 5: Simplified AAM Mode Control Logic



The AAM current (I_{AAM}) is set internally. The SW on-time pulse is determined by the on-timer generator and AAM comparator. If the AAM comparator pulse is longer than the on-timer generator pulse, then the part operates in AAM mode (see Figure 6).

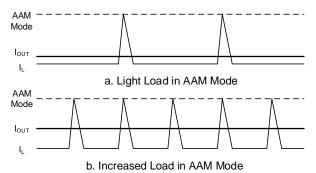


Figure 6: AAM Comparator Control On Time

If the AAM comparator pulse is shorter than the COT generator pulse, then the part operates in AAM mode (see Figure 7).

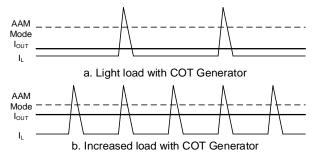
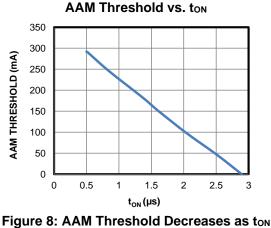


Figure 7: On-Timer Control On Time

Figure 8 shows that the AAM threshold decreases as t_{ON} increases gradually. In CCM, I_{OUT} should be at least half of the AAM threshold. Typically, the AAM threshold is below I_L during a normal duty cycle.



Increases

ZCD determines whether I_L has reversed. If I_L reaches the ZCD threshold, then the low-side MOSFET (LS-FET) turns off.

AAM mode and a ZCD circuit allow the MP2153D to operate in DCM at light loads, even if V_{OUT} is close to V_{IN} .

Enable (EN)

The enable (EN) pin enables and disables the MP2153D. Pull EN above 1.2V to turn the converter on; float EN or pull EN to GND to turn it off. If V_{IN} exceeds the under-voltage lockout (UVLO) threshold (typically 2.3V), then the part turns off. It can be turned on again once EN exceeds 1.2V. There is an internal 1M Ω resistor connected between the EN pin and GND.

If the MP2153D turns off, then the IC enters output discharge mode. Its internal discharge MOSFET provides a resistive discharge path for the output capacitor (C2).

Soft Start (SS)

The MP2153D has a built-in soft start (SS) that ramps up V_{OUT} at a controlled slew rate to avoid overshoot during start-up. The soft-start time (t_{SS}) is typically 0.5ms.

Current Limit

The MP2153D's HS-FET has a 6A maximum current limit (I_{LIMIT}). If the HS-FET exceeds its current limit, then the MP2153D operates in hiccup mode until the current drops below 6A. This prevents I_{L} from rising and damaging components.

Short Circuit Protection (SCP) and Recovery

If I_{LIMIT} has been exceeded, then short-circuit protection (SCP) is triggered. SCP hiccup mode is used to recover from the over-current (OC) fault. In hiccup mode, the output power stage is disabled and the soft-start capacitor (C_{SS}) is discharged, then the IC initiates an SS. If the short circuit remains once SS is complete, then the IC repeats the operation until the short circuit is removed and V_{OUT} rises to its regulation level.

Output Over-Voltage Protection (OVP)

The MP2153D monitors V_{FB} to detect overvoltage (OV) faults. If V_{FB} exceeds 115% of its target voltage, then the converter enters a dynamic regulation period. During this period,



the LS-FET turns off once the LS-FET current (I_{LS-FET}) drops to -1.5A. This discharges V_{OUT} to keep it within its normal range. If the OV condition remains, then the LS-FET turns on after a delay (1µs). The MP2153D exits this regulation period once the V_{FB} drops below 105% of V_{REF} .

If the dynamic regulation cannot limit the increasing V_{OUT} once V_{IN} exceeds 6.1V, then input over-voltage protection (OVP) is triggered. The MP2153D stops switching until V_{IN} drops below 5.7V. Once V_{IN} drops below 5.7V, then the IC resumes normal operation.



APPLICATION INFORMATION

Setting the Output Voltage

The external resistor divider sets V_{OUT} (see Figure 11 on page 17). Choose a FB resistor (R1) that reduces the V_{OUT} leakage current to between 100k Ω and 200k Ω . There is no strict requirement for the R1. The FB resistor (R2) can then be calculated with Equation (2):

$$R2 = \frac{R1}{\frac{V_{OUT}}{0.6} - 1}$$
 (2)

Where R1 is $10k\Omega$.

Figure 9 shows the feedback circuit.

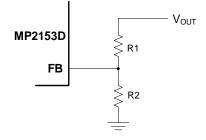


Figure 9: Feedback Network

Table 1 lists recommended resistor values for common output voltages.

Table 1: Resistor Values for Common Output Voltages

	0	
Vоит (V)	R1 (kΩ)	R2 (kΩ)
1	200 (1%)	300 (1%)
1.2	200 (1%)	200 (1%)
1.8	200 (1%)	100 (1%)
2.5	200 (1%)	63.2 (1%)
3.3	200 (1%)	44.2 (1%)

Selecting the Inductor

Select an inductor with a DC resistance below $50m\Omega$ to improve efficiency. For most applications, a 1µH to 2.2µH inductor is sufficient.

A high-frequency, switch-mode power supply with a magnetic device has strong electromagnetic inference. Unshielded power inductors should not be used in application. It is recommended to use metal alloy or multi-layer chip shielded power inductors, as they can reduce the electromagnetic interference. For most designs, the inductance (L_1) can be calculated with Equation (3):

$$L_{1} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_{L} \times f_{SW}}$$
(3)

Where ΔI_L is the inductor ripple current.

Choose I_L to be approximately 30% of the maximum load current (I_{LOAD_MAX}) . The maximum inductor peak current $(I_{L_PEAK_MAX})$ can be calculated with Equation (4):

$$\mathbf{I}_{\text{L}_{\text{PEAK}_{\text{MAX}}}} = \mathbf{I}_{\text{LOAD}} + \frac{\Delta \mathbf{I}_{\text{L}}}{2}$$
(4)

MPS inductors are optimized and tested for use with our complete line of integrated circuits. Table 2 lists our power inductor recommendations.

Table 2: Power Inductor Selection

Part Number	Inductance	Manufacturer
MPL-AL4020-1R0	1µH	MPS

Visit MonolithicPower.com under Products > Inductors for more information.

Selecting the Input Capacitor (C1)

The step-down converter has a discontinuous input current, and requires a capacitor to supply AC current to the step-down converter while maintaining the DC $V_{\rm IN}$. Use low ESR capacitors for the best performance. Ceramic capacitors with X5R or X7R dielectrics are recommended due to their low ESR and small temperature coefficients. For most applications, a 22µF capacitor is sufficient. Higher output voltages may require a 44µF capacitor to increase system stability.

C1 requires an adequate ripple current rating to absorb the switching I_{IN} . The RMS current in C1 (I_{C1}) can be estimated with Equation (5):

$$I_{C1} = I_{LOAD} \times \sqrt{\frac{V_{OUT}}{V_{IN}}} \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$
(5)

The worst case condition occurs at $V_{IN} = 2V_{OUT}$, which can be calculated with Equation (6):

$$I_{C1} = \frac{I_{LOAD}}{2}$$
(6)



For simplification, choose an input capacitor with an RMS current rating greater than half of I_{LOAD_MAX} . C1 can be electrolytic, tantalum, or ceramic.

When using electrolytic or tantalum capacitors, add a small, high-quality, 0.1μ F ceramic capacitor as close to the IC as possible.

When using ceramic capacitors, ensure that they have enough capacitance to provide a sufficient charge and prevent excessive voltage ripple at the input. The input voltage ripple (ΔV_{IN}) caused by the capacitance can be estimated with Equation (7):

$$\Delta V_{\text{IN}} = \frac{I_{\text{LOAD}}}{f_{\text{SW}} \times C1} \times \frac{V_{\text{OUT}}}{V_{\text{IN}}} \times \left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}\right)$$
(7)

Selecting the Output Capacitor (C2)

The output capacitor (C2) stabilizes the DC V_{OUT} . Low ESR ceramic capacitors are recommended to limit ΔV_{OUT} . ΔV_{OUT} can be estimated with Equation (8):

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{f_{\text{SW}} \times L_{1}} \times \left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}\right) \times \left(R_{\text{ESR}} + \frac{1}{8 \times f_{\text{SW}} \times C2}\right) (8)$$

Where R_{ESR} is the equivalent series resistance (ESR) of C2.

When using ceramic capacitors, the capacitance dominates the impedance at f_{SW} and causes most of ΔV_{OUT} . For simplification, ΔV_{OUT} can be estimated with Equation (9):

$$\Delta V_{OUT} = \frac{V_{OUT}}{8 \times f_{SW}^2 \times L_1 \times C2} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (9)$$

For tantalum or electrolytic capacitors, the ESR dominates the impedance at f_{SW} . For simplification, ΔV_{OUT} can be estimated with Equation (10):

$$\Delta V_{OUT} = \frac{V_{OUT}}{f_{SW} \times L_{1}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \times R_{ESR} \quad (10)$$

The characteristics of C2 also affect the stability of the regulation system.

PCB Layout Guidelines

Efficient PCB layout is critical for stable operation. A poor layout design can result in poor line and load regulation, as well as stability issues. For the best results, refer to Figure 10 and follow the guidelines below:

- 1. Place the high-current paths (GND, VIN, and SW) as close to the device as possible using short, direct, and wide traces.
- 2. Place the input capacitor (C1) as close to VIN and GND as possible.
- 3. Place the external feedback resistors close to the FB pin.
- 4. Keep the switching node (SW) short and away from the feedback network.
- 5. Keep the output voltage sense line as short as possible and away from the power inductor, especially the surrounding inductor.

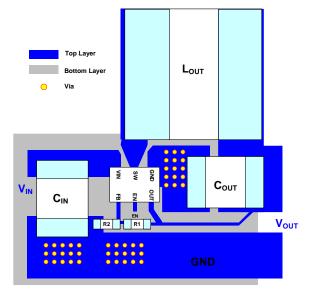


Figure 10: Recommended PCB Layout



TYPICAL APPLICATION CIRCUIT

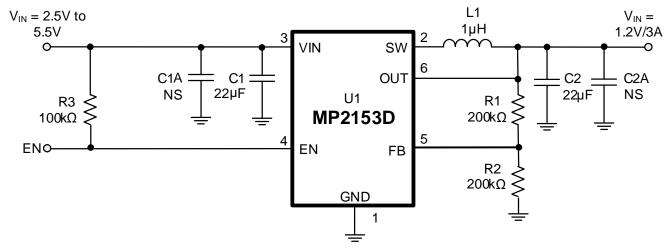


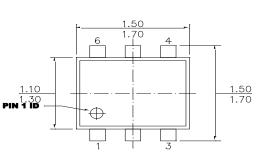
Figure 11: Typical Application Circuit (11)

Note:

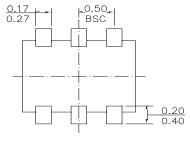
11) If V_{IN} is below 3.3V, then the application circuit may require more input capacitors.



PACKAGE INFORMATION







TOP VIEW

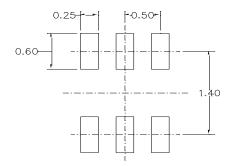




FRONT VIEW







NOTE:

1) ALL DIMENSIONS ARE IN MILLIMETERS.

2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR.

3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.

4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.10 MILLIMETERS MAX.

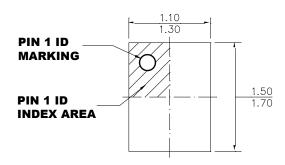
5) DRAWING IS NOT TO SCALE.

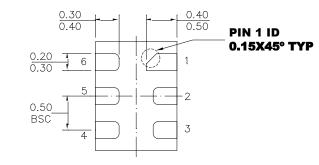
RECOMMENDED LAND PATTERN



PACKAGE INFORMATION (continued)

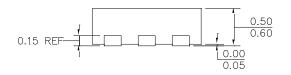
UTQFN-6 (1.2mmx1.6mm)



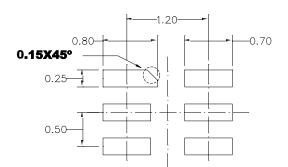


TOP VIEW









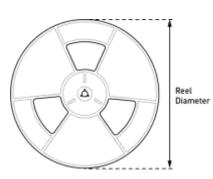
NOTE:

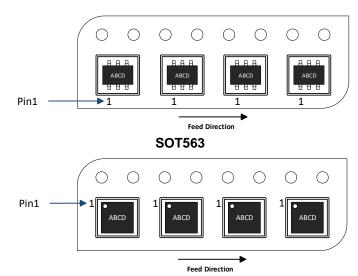
 ALL DIMENSIONS ARE IN MILLIMETERS.
LEAD COPLANARITY SHALL BE 0.08 MILLIMETERS MAX.
JEDEC REFERENCE IS MO-220.
DRAWING IS NOT TO SCALE.

RECOMMENDED LAND PATTERN



CARRIER INFORMATION





UTQFN-6 (1.2mmx1.6mm)

Part Number	Package Description	Quantity/ Reel	Quantity/ Tube	Reel Diameter	Carrier Tape Width	Carrier Tape Pitch
MP2153DGTF-Z	SOT563	5000	N/A	7in	8mm	4mm
MP2153DQFU-Z	UTQFN-6 (1.2mmx1.6mm)	5000	N/A	13in	8mm	4mm



REVISION HISTORY

R	evision #	Revision Date	Description	Pages Updated
	1.0	2/15/2022	Initial Release	-

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